

1 A Constant-Current LED Driver with PWM Dimming



FEATURES

- Accurate 1 A current sink
- Up to 25 V operation on LED pin
- Low dropout 500 mV at 1 A
- LED current set by external resistor
- High resolution PWM dimming via EN/PWM
- "Zero" current Shutdown mode
- Thermal shutdown protection
- TO-263 5-lead package

APPLICATIONS

- High Power LED up to 1 A
- Architectural and General Lighting
- Automotive Lighting

ORDERING INFORMATION

Part	Package	Quantity	Package
Number		per Reel	Marking
CAT4101TV-T75	TO-263-5*	750	CAT4101TV

^{*} Lead Finish Matte-Tin

DESCRIPTION

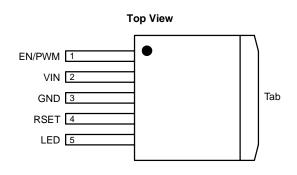
The CAT4101 is a constant-current sink driving a string of high-brightness LEDs up to 1 A with very low dropout of 0.5 V at full load. It requires no inductor, provides a low operation and minimizes the number of components. The LED current is set by an external resistor connected to the RSET pin. The LED pin is compatible with high voltage up to 25 V, allowing the driving of long strings of LEDs. The device ensures an accurate and regulated current in the LEDs independent of supply and LED forward voltage variation.

The PWM/EN input allows the device shutdown and the LED brightness adjustment by using an external pulse width modulation (PWM) signal.

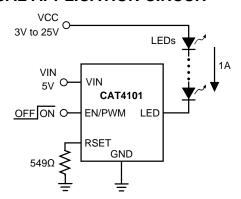
The driver features a thermal shutdown protection that becomes active whenever the die temperature exceeds 150°C.

The device is available in a high-power, 5-lead TO-263 package offerina excellent thermal dissipation characteristics.

PIN CONFIGURATION



TYPICAL APPLICATION CIRCUIT



ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
VIN, RSET, EN/PWM	6	V
LED Voltage	25	V
Storage Temperature Range	-65 to +160	°C
Junction Temperature Range	-40 to +150	°C
Lead Temperature	300	°C

RECOMMENDED OPERATING CONDITIONS

Parameter	Rating	Units
VIN	3.0 to 5.5	V
Ambient Temperature Range	-40 to +85	°C
LED Pin Current	Up to 1	A

Typical application circuit with external components is shown on page 1.

ELECTRICAL OPERATING CHARACTERISTICS

Min and Max values in bold are over recommended operating conditions unless specified otherwise. Typical values are at $V_{IN} = 5.0 \text{ V}$, $T_{AMB} = 25^{\circ}\text{C}$

Symbol	Name	Conditions	Min	Тур	Max	Units	
		$V_{LED} = 1 \text{ V}, \text{ RSET} = 1.47 \text{ k}\Omega$	315	350	385		
I _{LED-ACC}	LED Current Accuracy	$V_{LED} = 1 \text{ V, RSET} = 750 \Omega$		700		mA	
		$V_{LED} = 1 \text{ V, RSET} = 549 \Omega$		1000			
V _{DOUT}	Dropout Voltage	I _{LED} = 1 A		500		mV	
V _{RSET}	RSET Pin Voltage		1.17	1.20	1.23	V	
1	Quiggeont Current	No LED, RSET = Floating		0.8			
ΙQ	Quiescent Current	No LED, RSET = 549Ω		8.0		mA	
I _{QSHDN}	Shutdown Current	V _{EN} = 0 V			1	μΑ	
R _{EN/PWM} V _{HI} V _{LO}	EN/PWM PinPull-down resistanceLogic High LevelLogic Low Level		1.3	200	0.4	kΩ V V	
T _{SD}	Thermal Shutdown			150		°C	
T _{HYS}	Thermal Hysteresis			20		°C	
I _{LED} /I _{RSET}	RSET to LED Current gain ratio	100 mA LED current		400			
V _{UVLO}	Undervoltage lockout (UVLO) Threshold			2.0		V	

RECOMMENDED EN/PWM TIMING

For 3.0 V \leq VIN \leq 5.5 V, over full ambient temperature range -40°C to +85°C.

Symbol	Name	Conditions	Min	Тур	Max	Units
T _{PS}	Turn-On time, EN/PWM rising to I _{LED} from Shutdown	$I_{LED} = 1 A$ $I_{LED} = 350 \text{ mA}$		1.6 1.1		μs
T _{P1}	Turn-On time, EN/PWM rising to I _{LED}	$I_{LED} = 1 A$ $I_{LED} = 350 \text{ mA}$		920 620		ns
T _{P2}	Turn-Off time, EN/PWM falling to I _{LED}	$I_{LED} = 1 A$ $I_{LED} = 350 \text{ mA}$		440 310		ns
T_R	LED rise time	$I_{LED} = 1 A$ $I_{LED} = 350 \text{ mA}$		840 390		ns
T _F	LED fall time	$I_{LED} = 1 A$ $I_{LED} = 350 \text{ mA}$		470 350		ns
T _{LO}	EN/PWM low time		1	_		μs
T _{HI}	EN/PWM high time		5			μs
T _{PWRDWN}	EN/PWM low time to shutdown delay				8	ms

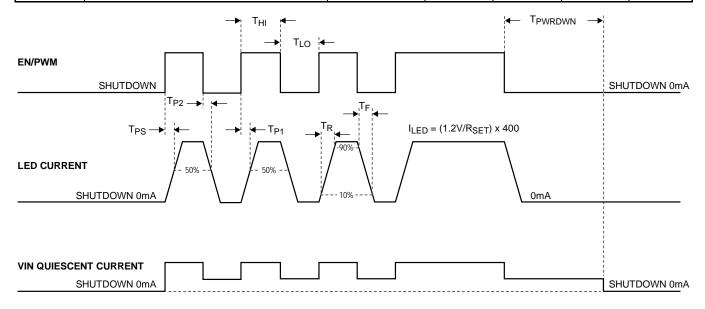


Figure 1. CAT4101 EN/PWM Timing

EN/PWM OPERATION

The EN/PWM pin has two primary functions. One function enables and disables the device. The other function turns the LED channel on and off for PWM dimming control. The device has a very fast turn-on time (from EN/PWM rising to LED on) and allows "instant on" when dimming LED using a PWM signal.

Accurate linear dimming is compatible with PWM frequencies from 100 Hz to 5 kHz for PWM duty cycle down to 1%. PWM frequencies up to 50 kHz can be supported for duty cycles greater than 10%.

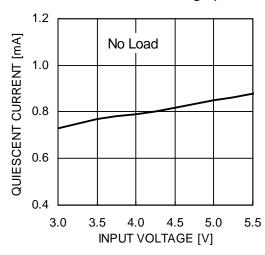
When performing a combination of low frequencies and small duty cycles, the device may enter shutdown mode. This has no effect on the dimming accuracy, because the turn-on time T_{PS} is very short, in the range of 1 μ s.

To ensure that PWM pulses are recognized, pulse width low time T_{LO} should be longer than $1\mu s$. The CAT4101 enters a "zero current" shutdown mode after a 5 ms delay (typical) when EN/PWM is held low.

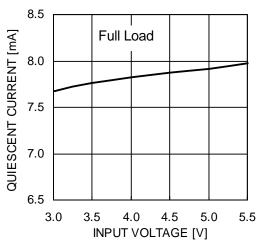
TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN} = 5 \text{ V}$, $V_{CC} = 5 \text{ V}$, $V_F = 3.5 \text{ V}$, $I_{LED} = 1 \text{ A}$ (1 LED), $C_{IN} = 1 \mu F$, $T_{AMB} = 25 ^{\circ}C$ unless otherwise specified.

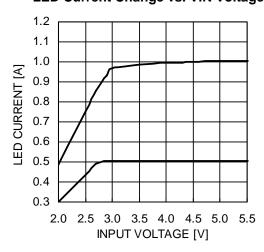
Quiescent Current vs. VIN Voltage (I_{LED} = 0 mA)



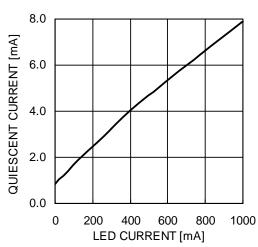
Quiescent Current vs. VIN Voltage (Full Load)



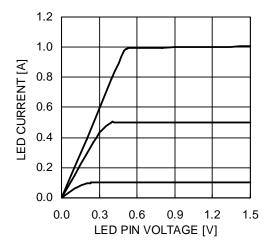
LED Current Change vs. VIN Voltage



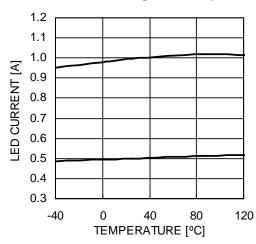
Quiescent Current vs. LED Current



LED Current vs. LED Pin Voltage



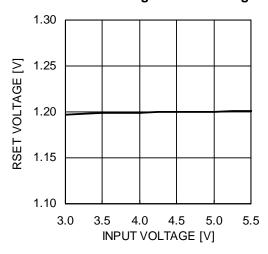
LED Current Change vs. Temperature



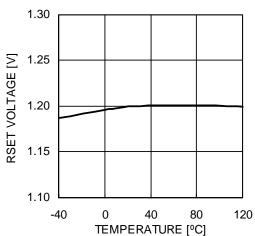
TYPICAL PERFORMANCE CHARACTERISTICS

 V_{IN} = 5 V, V_{CC} = 5 V, V_F = 3.5 V, I_{LED} = 1 A (1 LED), C_{IN} = 1 μF , T_{AMB} = 25 °C unless otherwise specified.

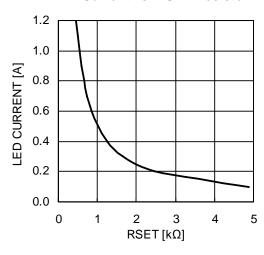
RSET Pin Voltage vs. VIN Voltage



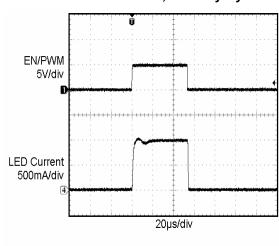
RSET Pin Voltage vs. Temperature



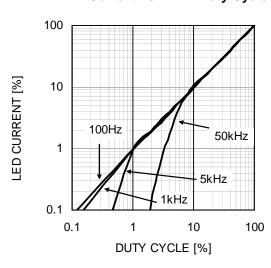
LED Current vs. RSET Resistor



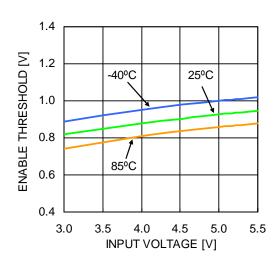
PWM 200 Hz, 1% Duty Cycle



LED Current vs. PWM Duty Cycle



EN/PWM Threshold vs. VIN



PIN DESCRIPTIONS

Name	Pin	Function
EN/PWM	1	Device enable (active high) and PWM control.
VIN	2	Device supply input, connect to battery or supply.
GND	3	Ground reference.
RSET	4	A resistor connected between this pin and ground sets the LED current.
LED	5	Bottom LED cathode terminal.
TAB	_	Connect TAB to the Ground plane.

PIN FUNCTION

VIN is the supply pin for the device. A small $0.1\,\mu\text{F}$ ceramic bypass capacitor is optional for noisy environments. The maximum operating voltage is $6.0\,\text{V}$. Whenever the input supply falls below the under-voltage threshold, the current sink will automatically be disabled.

EN/PWM is the enable and one wire dimming input for the LED channel. Guaranteed levels of logic high and logic low are set at 1.3 V and 0.4 V respetively. When EN/PWM is initially taken high, the device becomes enabled and the LED current is set at a gain of 400 times the current in RSET. To place the device into zero current shutdown mode, the EN/PWM pin must be held low for 5 ms typical.

LED pin is conneted to the bottom LED cathode and provides a regulated current sink. The pin enters a

high-impedance zero-current state whenever the device is placed in shutdown mode.

RSET pin is connected to an external resistor to set the LED current. The ground side of the external resistor should be star connected to the GND of the PCB. The pin source current mirrors the current to the LED sink. The voltage at this pin is regulated to 1.2 V.

GND is the ground reference for the device. The pin must be connected to the ground plane on the PCB.

TAB is the exposed pad underneath the package. For best thermal performance, the tab should be soldered to the PCB and connected to the ground plane.

BLOCK DIAGRAM

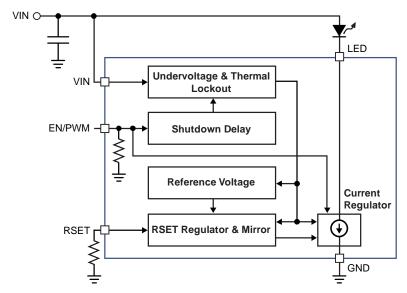


Figure 2. CAT4101 Functional Block Diagram

BASIC OPERATION

The CAT4101 has one highly accurate LED current sink to regulate LED current in a string of LEDs. The LED current is mirrored from the current flowing from the RSET pin according to the following formula:

$$I_{LED} \cong 400 \! \times \! \frac{1.2 \, V}{R_{SET}}$$

The LED channel needs a minimum of 500 mV headroom to sink constant regulated current. If the input supply falls below 2 V, the under-voltage lockout circuit disables the LED channel.

For applications requiring current higher than 1 A, several CAT4101 devices can be connected in parallel.

The LED channel can withstand and operate at voltages up to 25 V. This makes the device ideal for driving long strings of high power LEDs from a high voltage source.

Table 1. RSET Resistor Settings

LED Current [mA]	RSET [Ω]
100	4870
350	1470
700	750
1000	549

APPLICATION INFORMATION

SINGLE 12 V SUPPLY

The circuit shown in Figure 3 shows how to power three LEDs in series from a single 12 V supply using the CAT4101. The CAT4101 can not be driven directly from 12 V, three components are needed to create a lower voltage for the VIN pin (below 5.5 V). Resistor R2 and zener diode D provide a regulated voltage while the quiescent current runs through the N-Channel transistor M. Suitable parts for this circuit are the ON Semiconductor MM3Z6V2 zener diode and the 2N7002L N-channel transistor (SOT23 package).

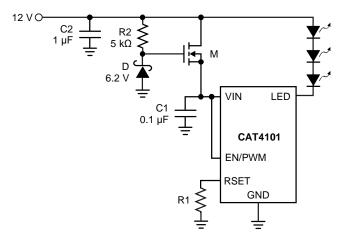


Figure 3. Single Supply Driving Three LEDs

POWER DISSIPATION

The power dissipation (P_D) of the CAT4101 can be calculated as follows:

$$P_{D} = (V_{IN} \times I_{IN}) + (V_{IED} \times I_{IED})$$

where V_{LED} is the voltage at the LED pin. Combinations of high V_{LED} voltage or high ambient temperature can cause the CAT4101 to enter thermal shutdown. In applications where V_{LED} is high, a resistor can be inserted in series with the LED string to lower P_{D} .

Thermal dissipation of the junction heat consists primarily of two paths in series. The first path is the junction to the case (θ_{JC}) thermal resistance which is defined by the package style, and the second path is the case to ambient (θ_{CA}) thermal resistance, which is dependent on board layout. The overall junction to ambient (θ_{JA}) thermal resistance is equal to:

$$\theta_{\text{JA}} = \theta_{\text{JC}} + \theta_{\text{CA}}$$

For a given package style and board layout, the operating junction temperature T_J is a function of the power dissipation P_D , and the ambient temperature, resulting in the following equation:

$$T_J = T_{AMB} + P_D (\theta_{JC} + \theta_{CA}) = T_{AMB} + P_D \theta_{JA}$$

The CAT4101 TO-263 5-lead package provides a thermal resistance when the ground tab is soldered down to the PCB. When mounted on a double-sided printed circuit board with two square inches of copper allocated for "heat spreading", the resulting θ_{JA} is about 30°C/W.

For example, at 60°C ambient temperature, the maximum power dissipation is calculated as follow:

$$P_{Dmax} = \frac{T_{Jmax} - T_{AMB}}{\theta_{JA}} = \frac{150 - 60}{30} = 3W$$

RECOMMENDED LAYOUT

The board layout should provide good thermal dissipation through the PCB. Multiple via can be used to connect the tab of the CAT4101 to a large ground plane underneath the package.

Input capacitor C1 should be placed as close to the driver IC as possible. The RSET resistor should have a Kelvin connection to the GND pin of the CAT4101.

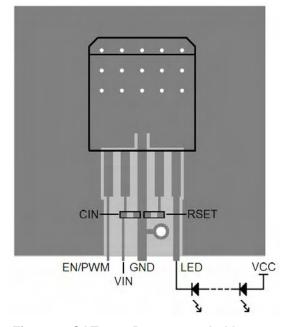
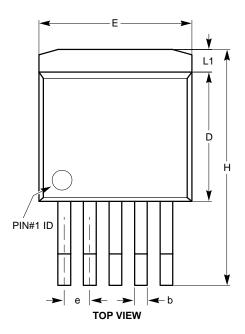


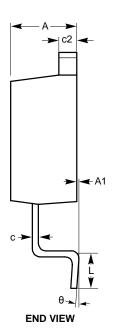
Figure 4. CAT4101 Recommended Layout

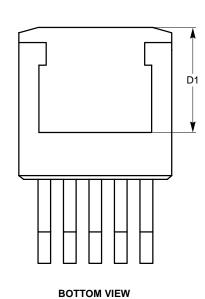
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PACKAGE OUTLINE DRAWING

TO-263 5-Lead (TV) (1)(2)







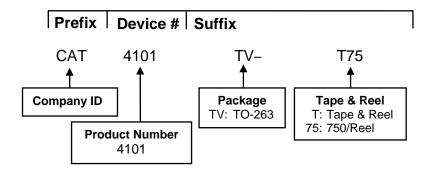
SYMBOL	MIN	NOM	MAX
Α	4.20		4.80
A1	0.00		0.25
b	0.60		0.88
С	0.33		0.50
c2	1.15		1.60
D	8.40		9.60
D1	6.86		
E	9.80		10.67
е		1.70 BSC	
Н	14.61		15.87
L	1.78		2.79
L1			1.67
А	00		80

For current Tape and Reel information, download the PDF file from: http://www.catsemi.com/documents/tapeandreel.pdf.

Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC standard TO-263.

EXAMPLE OF ORDERING INFORMATION



Notes:

- (1) All packages are RoHS-compliant (Lead-free, Halogen-free).
- (2) The standard plated finish is Matte-Tin.
- (3) The device used in the above example is a CAT4101TV-T75 (TO-263, Matte-Tin, Tape & Reel, 750/Reel).
- (4) For additional temperature options, please contact your nearest ON Semiconductor Sales office.

REVISION HISTORY

Date	Revision	Description	
21-Aug-08	Α	Initial Issue	
17-Nov-08	В	Change logo and fine print to ON Semiconductor	
03-Feb-09	С	Jpdate Application Information – Single 12 V Supply	
13-Mar-09	D	Updated Electrical Operating Characteristics Added new Typical Performance Characteristics Updated Block Diagram Updated Application Information – Single 12 V Supply	

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